## Supporting Information

## Super-Resolution Imaging of Photogenerated Charges on  $CdS/g-C<sub>3</sub>N<sub>4</sub>$  Heterojunctions and its Correlation with Photoactivity

Shuyang Wu, a Jinn-Kye Lee, a Pei Chong Lim, a Rong Xu, b Zhengyang Zhang a,\*

<sup>a</sup> Division of Chemistry and Biological Chemistry, School of Physical and Mathematical Sciences, Nanyang Technological University, 21 Nanyang Link, Singapore 637371.

**b** School of Chemical and Biomedical Engineering, Nanyang Technological University, 62 Nanyang Drive, Singapore 637459.

Corresponding Author E-mail: zhang.zy@ntu.edu.sg



**Fig. S1** XRD patterns of CdS, g-C3N4, CS/CN-II and CS/CN-Z.



**Fig. S2** Morphology of CdS and g-C3N4. FESEM and TEM images of (a, b) CdS and (c, d) g-

 $C_3N_4$ .



**Fig. S3** XPS survey spectra of (a) CdS, (b) g-C3N4, (c) CS/CN-II and (d) CS/CN-Z.



**Fig. S4** XPS spectra of (a) C 1s, (b) N 1s, (c) Cd 3d and (d) S 2p for CdS, g-C3N<sup>4</sup> and CS/CN-II.



**Fig. S5** UV-vis DRS spectra of CdS, g-C3N4, CS/CN-II, CS/CN-Z and physically mixed  $CdS/C<sub>3</sub>N<sub>4</sub>.$ 



**Fig. S6** Tauc plots of as-prepared samples for bandgap analysis.



**Fig. S7** UPS spectra of (a) CdS, (b)  $g-C_3N_4$ , (c) CS/CN-II and (d) CS/CN-Z.



Fig. S8 Photocatalytic H<sub>2</sub> generation for 6 h over CS/CN-II using different sacrificial reagents (50 mg CS/CN-II, 1 wt% Pt, 300 W Xe lamp, > 400 nm).



**Fig. S9** Charge distribution on CS/CN-II and CS/CN-Z. HRTEM images of CS/CN-II with (a) 1 wt% Pt and (b) 3 wt% PbO<sub>2</sub> loaded, and CS/CN-Z with (c) 1 wt% Pt and (d) 3 wt% PbO<sub>2</sub> loaded. Insets: HRTEM images of the marked positions in the respective images.



**Fig. S10** Percentages of Pt and Pb species after photo-deposition. XPS spectra of Pt 4f in 1 wt% Pt loaded (a) CS/CN-II and (b) CS/CN-Z. XPS spectra of Pb 4f in 3 wt% PbO<sub>2</sub> loaded (a) CS/CN-II and (b) CS/CN-Z.



**Fig. S11** Localize the center position of single fluorescent molecules with nanometer resolution. (a) Typical fluorescence image of a single resorufin molecule on CdS nanorods under laser excitation. (b) 2D Gaussian fitting of the fluorescence intensity profile with nanometer precision of  $\pm$  16 nm.

**Fig. S11a** is a typical fluorescence image of a single resorufin molecule on CdS nanorods. The fluorescence intensity spreads over a few pixels as a point spread function. Generally, the localization precision can be determined using the method reported in the previous work.<sup>1</sup> As shown in **Fig. S11b**, the center position can be determined by fitting the intensity signals with 2D elliptical Gaussian functions (**Eq. S1**):

$$
I(x,y) = A + B * exp_{x}^{[x]}(-\left(\frac{(x-x_0)^2}{2S_x^2} + \frac{(y-y_0)^2}{2S_y^2}\right))
$$
\n(S1)

where  $({}^{x_0}, {}^{y_0})$  is the center position, A is the background level, B is the peak intensity at  $({}^{x_0}, {}^{y_0})$  $y_0$ ,  $S_x$  and  $S_y$  are the standard deviations of the Gaussian distribution along the x- and y-axes, respectively. The localization precision  $(\sigma_{j},{}_{j=x,y})$  can be calculated based on the pixel size of the camera, the photons collected and background noise level using **Eq. S2**:

$$
\sigma_j = \sqrt{\left(\frac{S_j^2}{N} + \frac{a^2/12}{N} + \frac{8\pi S_j^4 b^2}{a^2 N^2}\right)}
$$
(S2)

where  $N$  is the photons collected,  $a$  is the pixel size, and  $b$  is the background noise in photons. In the example shown in **Fig. S11**, the parameters are determined to be  $S_x = 133$  nm,  $S_y = 131$ nm,  $a = 160$  nm,  $N = 612$  and  $b = 16$ . Thus,  $\sigma_x = 16$  nm and  $\sigma_y = 15$  nm are obtained. The average localization precision is calculated to be  $\sigma_{xy} = 16$  nm using **Eq. S3**:

$$
\sigma_{xy} = (\sigma_x + \sigma_y)/2 \tag{S3}
$$



**Fig. S12** (a, d) Conventional brightfield images, (b, e) SRM images and (c, f) density maps (bin size:  $25 \text{ nm} \times 25 \text{ nm}$ ) of pure CdS with resazurin. Scale bar: 1 µm.



**Fig. S13** Conventional brightfield images of pure CdS with amplex red (a) before irridiation and (b) after irradiation. Scale bar:  $1 \mu m$ .



**Fig. S14** (a, d) Conventional brightfield images, (b, e) SRM images and (c, f) density maps (bin size: 25 nm  $\times$  25 nm) of pure g-C<sub>3</sub>N<sub>4</sub> with resazurin. Scale bar: 1 µm.



**Fig. S15** (a, d) Conventional brightfield images, (b, e) SRM images and (c, f) density maps (bin size: 25 nm  $\times$  25 nm) of pure g-C<sub>3</sub>N<sub>4</sub> with amplex red (The dashed lines are the outlines of g-C<sub>3</sub>N<sub>4</sub> in the brightfield images). Scale bar: 1  $\mu$ m.



**Fig. S16** Conventional brightfield images of CS/CN-Z with amplex red (a) before irridiation and (b) after irradiation. Scale bar:  $1 \mu m$ .



**Fig. S17** HRTEM images of (a) CS/CN-II and (b) CS/CN-Z.



**Table S1.** Summary of typical CdS/g-C<sub>3</sub>N<sub>4</sub> composites for photocatalytic H<sub>2</sub> generation.

**Table S2.** Pt loading based on ICP measurement and percentages of Pt and Pb species observed from XPS spectra on CS/CN-II and CS/CN-Z after photoreactions.

	$1\%$ Pt <sup>a)</sup>			$3\%$ PbO <sub>2</sub>	
	Pt loading <sup>b)</sup> $(Pt^{0 c}) (%)$	$Pt^{0}$ (%)	$Pt^{2+}($ %)	$Pb^{4+}($ %)	$Pb^{2+}($ %)
CS/CN-II	0.79(0.69)	87.4	12.6	93.1	6.9
$CS/CN-Z$	0.71(0.56)	79.5	20.5	89.0	11.0

<sup>a)</sup> Theoretical loading based on the amount of Pt precursor is 1 wt%; <sup>b)</sup> by IPC measurement; <sup>c)</sup> total Pt% multiply by  $Pt^{00}$ % from XPS results.

## **Reference**

1. T.-X. Huang, B. Dong, S. L. Filbrun, A. A. Okmi, X. Cheng, M. Yang, N. Mansour, S. Lei and N. Fang, *Sci. Adv.*, 2021, **7**, eabj4452.

2. W. Li, C. Feng, S. Dai, J. Yue, F. Hua and H. Hou, *Appl. Catal. B: Environ.*, 2015, **168**, 465-471.

3. N. Güy, *Appl. Surf. Sci.*, 2020, **522**, 146442.

4. H. Pang, Y. Jiang, W. Xiao, Y. Ding, C. Lu, Z. Liu, P. Zhang, H. Luo and W. Qin, *J. Alloys Compd.*, 2020, **839**, 155684.

5. B. Chong, L. Chen, D. Han, L. Wang, L. Feng, Q. Li, C. Li and W. Wang, *Chinese J. Catal.*, 2019, **40**, 959-968.

6. K. Wang, X. Wang, H. Pan, Y. Liu, S. Xu and S. Cao, *Int. J. Hydrog. Energy*, 2018, **43**, 91-99.

7. Z. L. Fang, H. F. Rong, L. Y. Zhou and P. Qi, *J. Mater. Sci.*, 2015, **50**, 3057-3064.

8. H. Zhao, X. Ding, B. Zhang, Y. Li and C. Wang, *Sci. Bull.*, 2017, **62**, 602-609.

9. L. Qian, Y. Hou, Z. Yu, M. Li, F. Li, L. Sun, W. Luo and G. Pan, *Mol. Catal.*, 2018, **458**, 43-51.

10. Z. Wang, Z. Wang, X. Zhu, C. Ai, Y. Zeng, W. Shi, X. Zhang, H. Zhang, H. Si and J. Li, *Small*, 2021, 2102699.